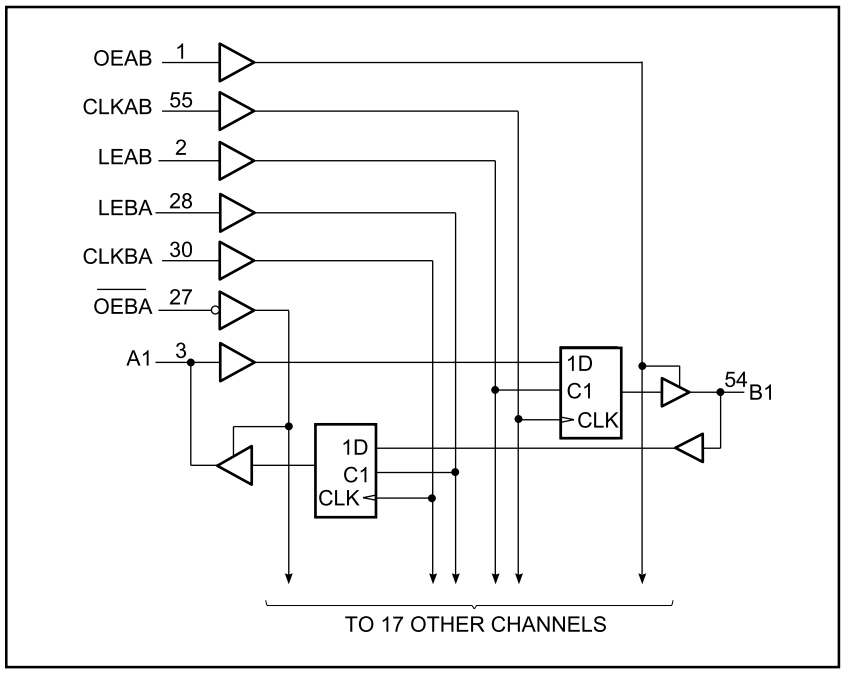
2.5V 18-Bit Universal Bus Transceiver With 3-State Outputs

Product Features

- PI74ALVTC16501 is designed for low voltage operation, V_{DD} = 1.65V to 3.6V
- Supports Live Insertion
- 3.6V I/O Tolerant Inputs and Outputs
- Bus Hold
- High Drive, –32/64mA @ 3.3V
- Uses patented noise reduction circuitry
- Power-off high impedance inputs and outputs
- Industrial operation at –40°C to +85°C
- Packages available:
  - 56-pin 240-mil wide plastic TSSOP (A)
  - 56-pin 173-mil wide plastic TVSOP (K)

Logic Block Diagram



Product Description

Pericom Semiconductor's PI74ALVTC series of logic circuits are produced using the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

The 18-bit PI74ALVTC16501 univeral bus transceiver is designed for 1.65V to 3.6V V_{DD} operation.

Data flow in each direction is controlled by Output Enable (OEAB and $\overline{OEBA}$), Latch Enable (LEAB and LEBA), and CLOCK (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is LOW, the A-bus data is stored in the latch/flip-flop on the low-to-high transition of CLKAB. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high-impedance state.

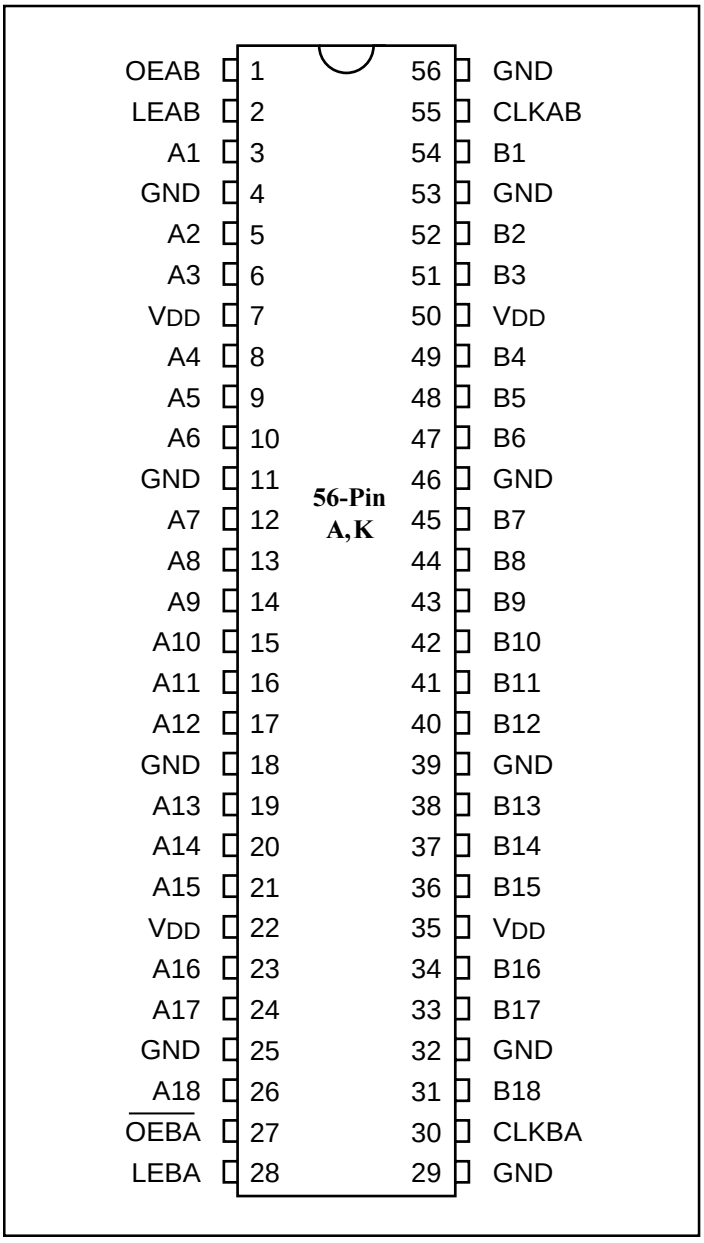
Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, LEBA, and CLKBA. The Output Enables are complementary (OEAB is active HIGH and $\overline{OEBA}$ is active LOW)

To ensure the high-impedance state during power up or power down, $\overline{OEBA}$ should be tied to V_{DD} through a pull-up resistor and OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active HIGH)
LE	Latch Enable (Active HIGH)
CLK	Clock Input (Active HIGH)
Ax	Data I/O
Bx	Data I/O
GND	Ground
V_{DD}	Power

Product Pin Configuration



Truth Table[(1)†]

Inputs				Output B
OEAB	LEAB	CLKAB	A	
L	X	X	X	Z
H	H	X	L	L
H	H	X	H	H
H	L	↑	L	L
H	L	↑	H	H
H	L	H	X	B0‡
H	L	L	X	B0§

Notes:

1. H = High Signal Level
   L = Low Signal Level
   Z = High Impedance
   ↑ = LOW-to-HIGH Transition

† A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, CLKBA.

‡ Output level before the indicated steady-state input conditions were established, provided that CLKAB is HIGH before LEAB goes LOW.

§ Output level before the indicated steady-state input conditions were established.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage Range, V_{DD} ..... –0.5V to 4.6V
Input Voltage Range, V_I ..... -0.5V to 4.6V
Output Voltage Range, V_O (3-Stated) ..... -0.5V to 4.6V
Output Voltage Range, V_O[1] (Active) ..... –0.5V to V_{DD} +0.5V
DC Input Diode Current (I_{IK}) $V_I < 0V$ ..... -50mA
DC Output Diode Current (I_{OK})
$V_O < 0V$ ..... -50mA
$V_O > V_{DD}$ ..... ±50mA
DC Output Source/Sink Current (I_{OH}/I_{OL}) ..... -64/128mA
DC V_{DD} or GND Current per Supply Pin (I_{CC} or GND) ..... ±100mA
Storage Temperature Range, T_{stg} ..... –65°C to 150°C

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions[2]

			Min.	Max.	Units
V_{DD}	Supply voltage	Operating	1.65	3.6	V
		Data Retention Only	1.2	3.6	
V_{IH}	High-level input voltage	V_{DD} = 2.7V to 3.6V	2.0		
V_{IL}	Low-level input voltage	V_{DD} = 2.7V to 3.6V		0.8	
V_I	Input voltage		–0.3	3.6	
V_O	Output voltage	Active State	0	V_{DD}	
		Off State	0	3.6	
	Output current in I_{OH}/I_{OL}	V_{DD} = 3.0V to 3.6V V_{DD} = 3.0V to 3.6V V_{DD} = 2.3V to 2.7V V_{DD} = 1.65V to 1.95V		–32/64 ±24 ±18 ±6	mA
$\Delta t/\Delta v$	Input transistion rise or fall rate[3]		0	10	ns/V
T_A	Operating free-air temperature		–40	85	C

Notes:
1. Absolute maximum of I_O must be observed.
2. Unused control inputs must be held HIGH or LOW to prevent them from floating.
3 As measured between 0.8V and 2.0V, V_{DD}=3.0V.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted)

DC Characteristics ($2.7V < V_{DD} \leq 3.6V$)

	Parameter	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	I_{IK} = –18mA	3.0			–1.2	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	2.7 - 3.6	V_{DD} – 0.2			
		I_{OH} = –12mA	2.7	2.2			
		I_{OH} = –18mA	3.0	2.4			
		I_{OH} = –24mA		2.2			
		I_{OH} = –32mA		2.0			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.7 - 3.6			0.2	
		I_{OL} = 12mA	2.7			0.4	
		I_{OL} = 18mA	3.0			0.4	
		I_{OL} = 24mA				0.45	
		I_{OL} = 32mA				0.5	
		I_{OL} = 64mA				0.75	
I_I	Input Leakage Current	$V_I = V_{DD}$, or GND	3.6			±5.0	µA
I_{OZ}	3-State Output Leakage	V_O = 3.6V	2.7			±10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq$ 3.6V	0			10	
I_{HOLD}	Bus Hold Current A or B Outputs	V_I = 0.8V	3.0	75			
		V_I = 2.0V		–75			
		V_I = 0 to 3.6V	3.6			±500	
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.7 - 3.6			50	
		$V_{DD} \leq (V_I, V_O) \leq$ 3.6V				±50	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD}$ –0.6V, Other inputs at V_{DD} or Gnd				400	

Electrical Characteristics over Recommended Operating Free-Air Temperature Range (unless otherwise noted)
(continued from previous page)

DC Characteristics ($2.3V \leq V_{DD} \leq 2.7V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	I_{IK} = –18mA	2.3			–1.2	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	2.3 -2.7	V_{DD}– 0.2			
		I_{OH} = –12mA	2.3	1.8			
		I_{OH} = –18mA		1.7			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 - 2.7			0.2	
		I_{OL} = 12mA	2.3			0.4	
		I_{OL} = 18mA				0.5	
		I_{OL} = 24mA				0.55	
I_I	Input Leakage Current	V_I = V_{DD} or GND	2.7			±5.0	µA
I_{OZ}	3-State Output Leakage	V_O = 3.6V	2.3			±10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq$ 3.6V	0			10	
I_{HOLD}[1]	Bus Hold Current A or B Outputs	V_I = 0.7V	2.5		90		µA
		V_I = 1.7V			–90		
I_{DD}	Quiescent Supply Current	V_I = V_{DD} or GND	2.3 - 2.7			40	
		$V_{DD} \leq (V_I, V_O) \leq$ 3.6V				±40	
ΔI_{DD}	Increase in I_{DD} per input	V_{IH} = V_{DD} –0.6V, Inputs at V_{DD} or Gnd				400	

Note:
1. Not Guaranteed

Electrical Characteristics over Recommended Operating Free-Air Temperature Range (unless otherwise noted)
(continued from previous page)

DC Characteristics ($1.65V \leq V_{DD} \leq 1.95V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	I_{IK} = –18mA	1.65			–1.2	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100µA	1.65-1.95	V_{DD} –0.2			
		I_{OH} = –6mA	1.65	1.4			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA				0.2	
		I_{OL} = 6mA				0.3	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	1.95			±5.0	µA
I_{OZ}	3-State Output Leakage	V_O = 3.6V	1.65			±10	
I_{OFF}	Power-OFF Leakage Current	$V_I = V_O \leq 3.6V$	0			10	
I_{HOLD}(1)	Bus Hold Current A or B Outputs	V_I = 0.4	1.65		50		
		V_I = 1.3			–50		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	1.65-1.95			20	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				±20	
ΔI_{DD}	Increase in I_{DD} per input	$V_I = V_{DD}$ –06V, Other inputs at V_{DD} or Gnd				400	

Note:
1. Not Guaranteed

Timing Requirements over recommended operating free-air temperature range

(unless otherwise noted, see Figures 1 thru 4)

			V_{DD} = 1.8V ±0.15V		V_{DD} = 2.5V ±0.2V		V_{DD} = 3.3V ±0.3V		Units
			Min.	Max.	Min	Max.	Min.	Max.	
f_{clock} Clock Frequency				150		180		180	MHz
t_w Pulse duration	LE High		2.0		1.5		1.5		ns
			3.5		3.0		2.0		
1.5	Data before CLK↑		2.5		2.0		2.0		
		CLK High	1.2		1.0		1.0		
		1.5	1.0		1.0		1.0		
	Data before CLK↑		1.0		1.0		1.0		
	Data after LE ↓	CLK High or Low	1.5		1.5		1.5		

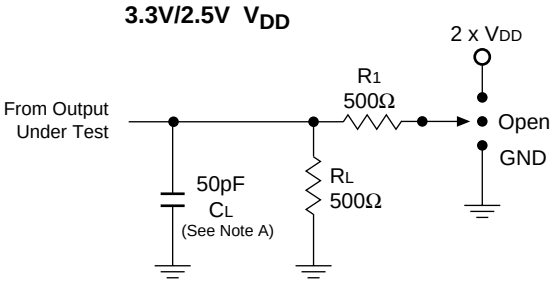
Switching Characteristics over recommended operating free-air temperature range

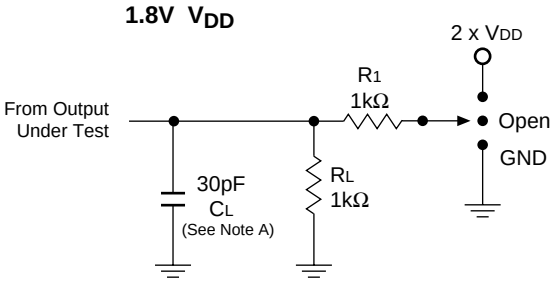
(unless otherwise noted, see Figures 1 thru 4)

Parameters	From (Input)	To (Output)	V_{DD} = 1.8V ±0.15V		V_{DD} = 2.5V ±0.2V		V_{DD} = 3.3V ±0.3V		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
f_{max}			150		180		180		MHz
t_{pd}	A or B	B or A	1.1	4.5	1.0	3.4	1.0	3.0	ns
	LE	A or B	2.1	5.0	2.0	4.0	1.5	3.4	
	CLK		1.3	5.0	1.0	4.5	1.0	3.2	
t_{en}	OEAB	B	1.2	4.5	1.0	4.0	1.0	3.1	
t_{dis}	OEAB	B	1.7	5.5	1.5	4.2	2.0	3.5	
t_{en}	$\overline{OEBA}$	A	1.7	5.0	1.5	4.5	1.0	3.1	
t_{dis}	$\overline{OEBA}$	A	1.7	5.5	1.5	4.2	2.0	4.0	

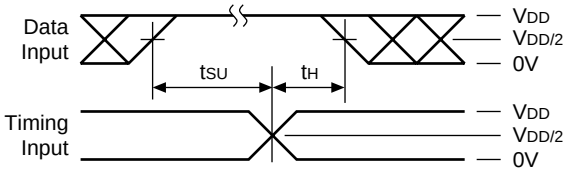
Test Circuits and Switching Waveforms

Parameter Measurement Information (V_{DD} = 1.65V - 3.6V)





Setup, Hold, and Release Timing



Notes:

A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.

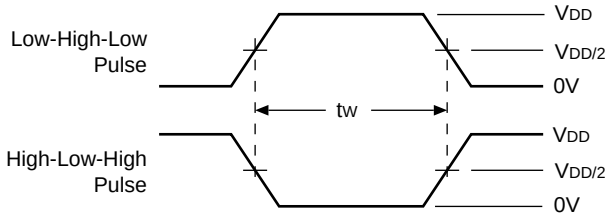
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50Ω, t_r ≤ 2ns, t_f ≤ 2ns, ***measured from 10% to 90%, unless otherwise specified.***

D. The outputs are measured one at a time with one transition per measurement.

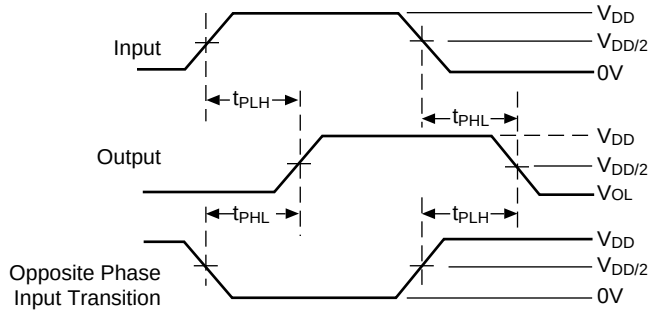
Switch Position

Test	S1
t_{PD}	Open
t_{PLZ}/t_{PZL}	2 x V_{DD}
t_{PHZ}/t_{PZH}	GND

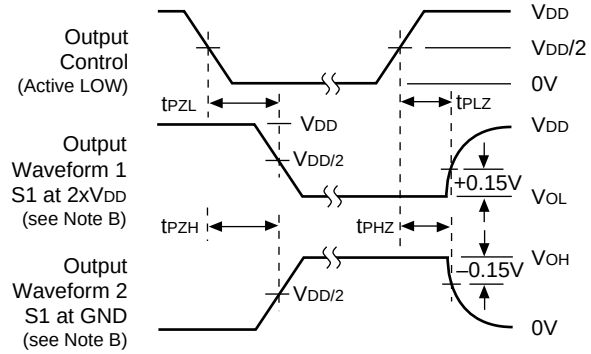
Pulse Width



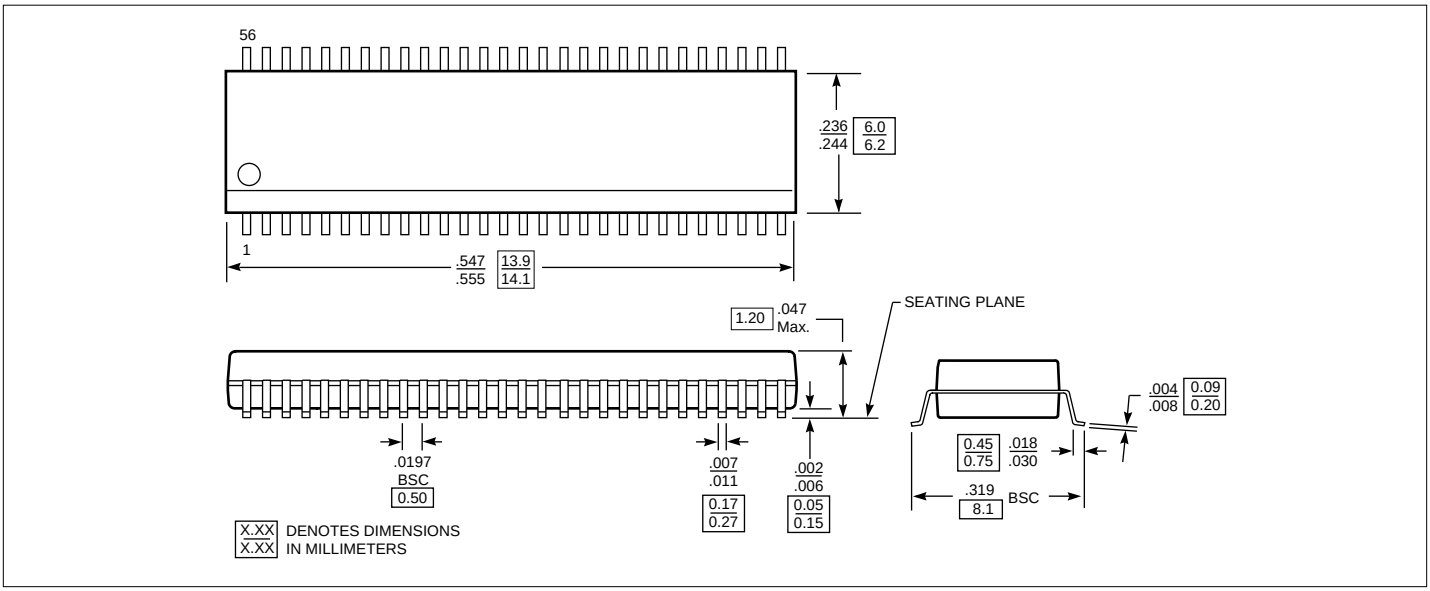
Propagation Delay



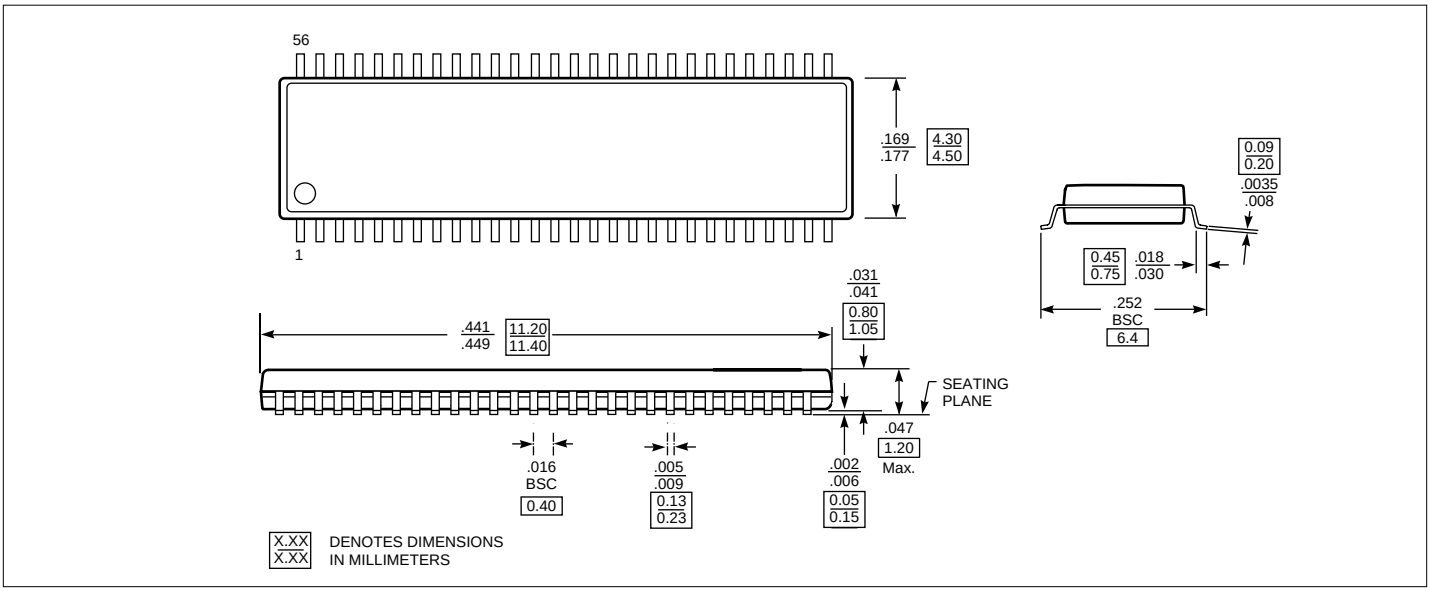
Enable Disable Timing



Packaging Mechanical: 56-pin TSSOP (A)



Packaging Mechanical: 56-pin TVSOP (K)



Ordering Information	Package - Pins
PI74ALVTC16501A	TSSOP - 56
PI74ALVTC16501K	TVSOP - 56